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EFS ID: 21554
Application ID: 09955641
Title of Invention: SEMICONDUCTOR MEMORY CELL AND
MEMORY ARRAY USING A BREAKDOWN
PHENOMENA IN AN ULTRA-THIN
DIELECTRIC
First Named Inventor: Jack Peng
Domestic/Foreign Application: Domestic Application
Filing Date: 2001-09-18
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Submission Type: Information
Disclosure Statement

Application Number: 09/955641
Attorney Docket Number: 384848001US

SEMICONDUCTOR MEMORY CELL AND MEMORY ARRAY USING A BREAKDOWN PHENOMENA IN AN ULTRA-THIN DIELECTRIC

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First Named Inventor: Jack Zezhong Peng

SUBMITTED BY

Name:	Chun M. Ng
Registration Number:	36,878
Electronic Signature Mark: /cmn	Date Signed: 20030107

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Attached Files:

us-information-disclosure-statement

8001USids.xml

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Electronic Information Disclosure Statement

SEMICONDUCTOR MEMORY CELL AND MEMORY ARRAY USING A BREAKDOWN PHENOMENA IN AN ULTRA-THIN DIELECTRIC

Application:



09/955641

Confirmation: 1777

Applicant(s): Jack Peng

Docket

384848001 US

Number:

Group Art

2818

Unit:

Examiner:

search string: (3634929 or 4322822 or 4488262 or 4502208 or 4507757 or 4543594 or 4613886 or 4823181 or 4876220 or 4899205 or 4943538 or 5138410 or 5304871 or 5412244 or 5496756 or 5576568 or 5587603 or 5600265 or 5675541 or 5825200 or 5825201 or 5880512 or 5909049 or 6084428 or 6097077 or 6421293).pn.

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US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

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Signature

Examiner Name	Date